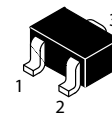
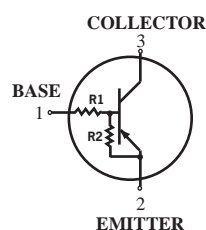


Bias Resistor Transistor PNP Silicon

 Lead(Pb)-Free



SOT-323(SC-70)

Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CE0}	50	Vdc
Collector-Base Voltage	V_{CB0}	50	Vdc
Collector Current-Continuous	I_C	100	mAdc

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (1) $T_A=25^\circ\text{C}$ Derate above 25°C	P_D	202 (1)	mW
		310 (2)	
		1.6 (1)	$\text{mW}/^\circ\text{C}$
		2.5 (2)	
Thermal Resistance, Junction to Ambient (1)	$R_{\theta JA}$	618 403	$^\circ\text{C}/\text{W}$
Junction and Storage, Temperature Range	$T_{J,Tstg}$	-55 to +150	$^\circ\text{C}$

1.FR-4 @ minimum pad

2.FR-4 @ 1.0×1.0 inch Pad

Device Marking and Resistor Values

Device	Marking	R1(K)	R2(K)	Device	Marking	R1(K)	R2(K)
MUN5111	6A	10	10	MUN5131	6H	2.2	2.2
MUN5112	6B	22	22	MUN5132	6J	4.7	4.7
MUN5113	6C	47	47	MUN5133	6K	4.7	47
MUN5114	6D	10	47	MUN5134	6L	22	47
MUN5115	6E	10	∞	MUN5135	6M	2.2	47
MUN5116	6F	4.7	∞	MUN5136	6N	100	100
MUN5130	6G	1.0	1.0	MUN5137	6P	47	22

Electrical Characteristics (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Unit
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On Characteristics (3)

DC Current Gain (VCE=-10V, IC=-5.0mA)	MUN5111	h _{FE}	35	60	-	
	MUN5112		60	100	-	
	MUN5113		80	140	-	
	MUN5114		80	140	-	
	MUN5115		160	250	-	
	MUN5116		160	250	-	
	MUN5130		3.0	5.0	-	
	MUN5131		8.0	15	-	
	MUN5132		15	27	-	
	MUN5133		80	140	-	
	MUN5134		80	130	-	
	MUN5135		80	140	-	
	MUN5136		80	150	-	
	MUN5137		80	140	-	
Output Voltage(on) (V _{CC} =5.0V, V _B =2.5V, R _L =1.0kΩ)	MUN5111	V _{OL}	-	-	0.2	V _{dc}
	MUN5112		-	-	0.2	
	MUN5113		-	-	0.2	
	MUN5114		-	-	0.2	
	MUN5115		-	-	0.2	
	MUN5116		-	-	0.2	
	MUN5130		-	-	0.2	
	MUN5131		-	-	0.2	
	MUN5132		-	-	0.2	
	MUN5133		-	-	0.2	
	MUN5134		-	-	0.2	
	(V _{CC} =5.0V, V _B =3.5V, R _L =1.0kΩ)		MUN5135	-	-	
(V _{CC} =5.0V, V _B =5.5V, R _L =1.0kΩ)	MUN5136	-	-	0.2		
(V _{CC} =5.0V, V _B =4.0V, R _L =1.0kΩ)	MUN5137	-	-	0.2		
Output Voltage(off) (V _{CC} =5.0V, V _B =0.5V, R _L =1.0kΩ) (V _{CC} =5.0V, V _B =0.05V, R _L =1.0kΩ) (V _{CC} =5.0V, V _B =0.25V, R _L =1.0kΩ)	MUN5130	V _{OH}	4.9	-	-	V _{dc}
	MUN5115					
	MUN5116					
	MUN5131					
	MUN5133					

3. Pulse Test: Pulse Width<300 us, Duty Cycle<2.0%

Electrical Characteristics (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Unit
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On Characteristics

Input Resistor	MUN5111	R1	7.0	10	13	kΩ
	MUN5112		15.4	22	28.6	
	MUN5113		32.9	47	61.1	
	MUN5114		7.0	10	13	
	MUN5115		7.0	10	13	
	MUN5116		3.3	4.7	6.1	
	MUN5130		0.7	1.0	1.3	
	MUN5131		1.5	2.2	2.9	
	MUN5132		3.3	4.7	6.1	
	MUN5133		3.3	4.7	6.1	
	MUN5134		15.4	22	28.6	
	MUN5135		1.54	2.2	2.86	
	MUN5136		70	100	130	
	MUN5137		32.9	47	61.1	
Resistor Ratio MUN5111/MUN5112/MUN5113	R1/R2	0.8	1.0	1.2		
MUN5136		0.17	0.21	0.25		
MUN5114		-	-	-		
MUN5115/MUN5116		0.8	1.0	1.2		
MUN5130/MUN5131/MUN5132		0.055	0.1	0.185		
MUN5133		0.38	0.47	0.56		
MUN5134		0.038	0.047	0.056		
MUN5135		1.7	2.1	2.6		

4. Pulse Test: Pulse Width < 300 us, Duty Cycle < 2.0 %

MUN5111T1 Series

ALL MUN5111 SERIES DEVICES

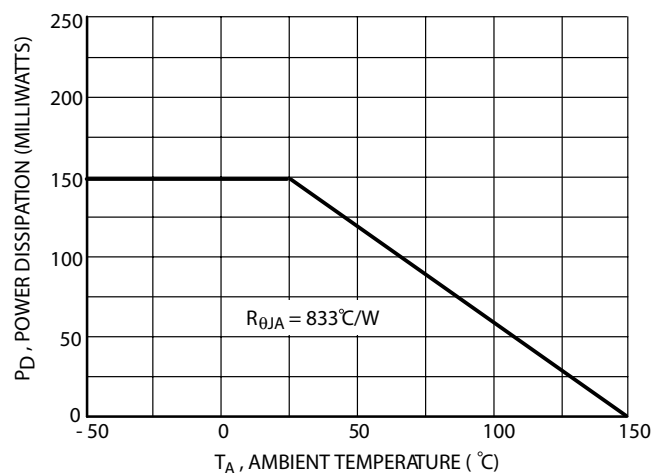


FIG.1 Derating Curve

MUN5111 Series

TYPICAL ELECTRICAL CHARACTERISTICS-MUN5135

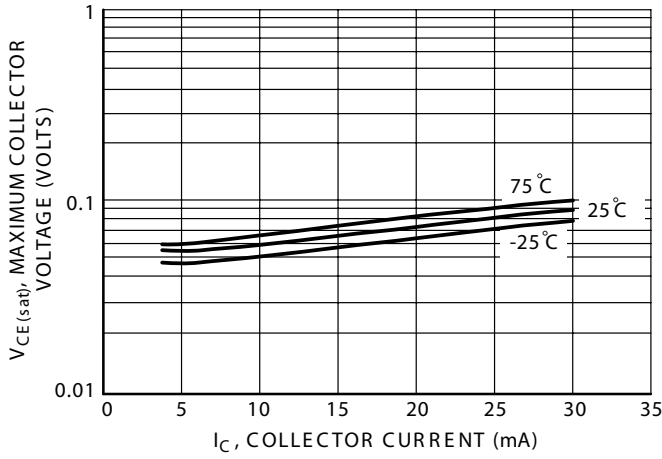


FIG.2 Maximum Collector Voltage versus Collector Current

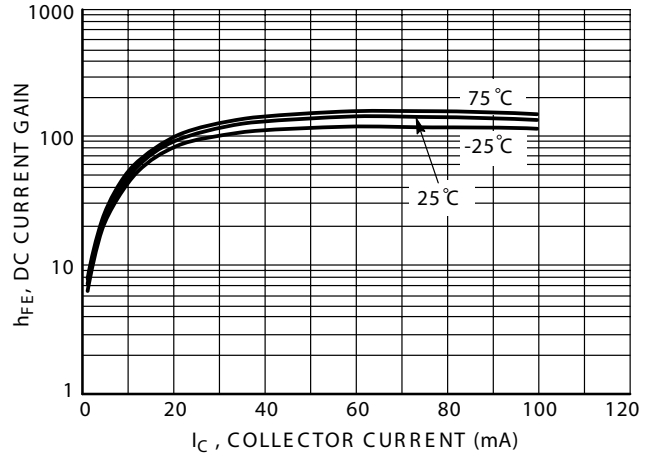


FIG.3 DC Current Gain

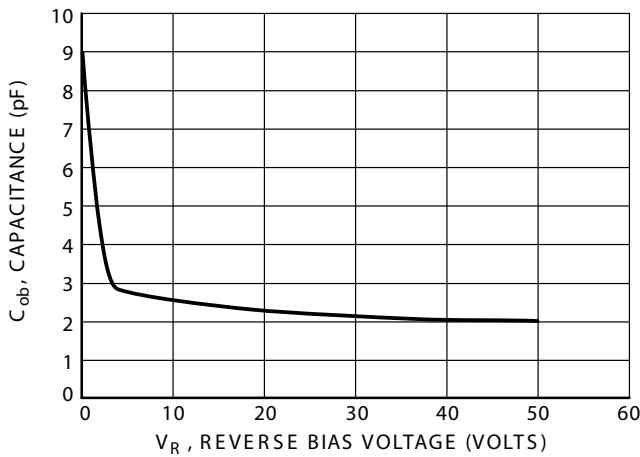


FIG.4 Output Capacitance

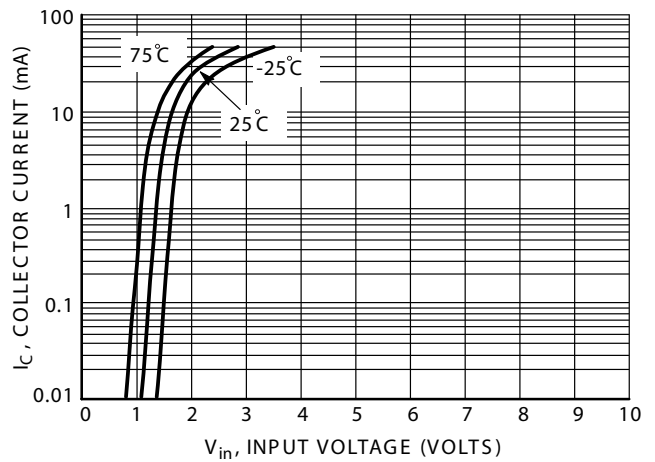


FIG.5 Output Current versus Input Voltage

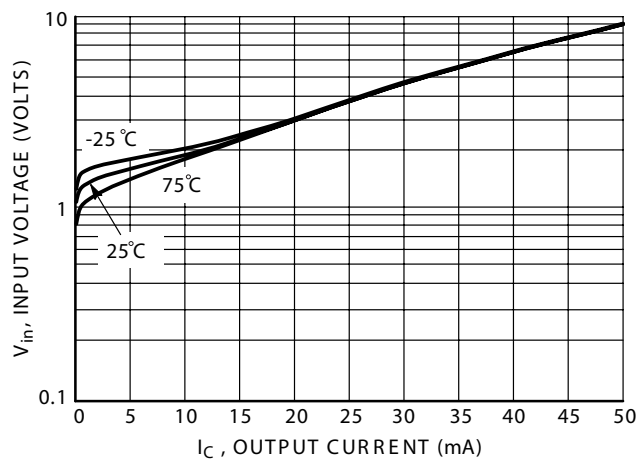
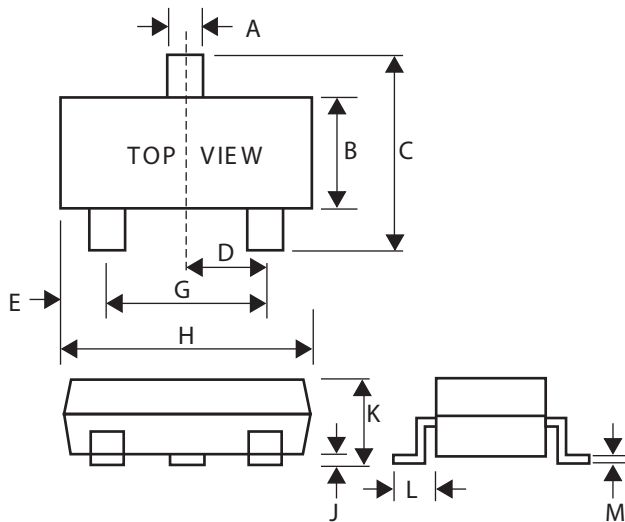


FIG.6 Input Voltage versus Output Current

SOT-323 Outline Demensions

Unit:mm



SOT-323		
Dim	Min	Max
A	0.30	0.40
B	1.15	1.35
C	2.00	2.40
D	-	0.65
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.00	0.10
K	0.80	1.00
L	0.42	0.53
M	0.10	0.25